

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,501,582 B2
APPLICATION NO. : 10/790363
DATED : March 10, 2009
INVENTOR(S) : McDermott et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 9, line 35, after the, delete "top".

Column 10, line 14, after surface, insert -- , --.

Column 11, line 31, insert -- a -- before portion.

Column 11, lines 35-36, delete "cavities are obtusely angled and".

Column 12, line 47, delete "top".

Column 17, line 21, delete "top".

Column 24, line 33, delete "method" and there insert -- process --.

Column 24, line 38, add the following claims:

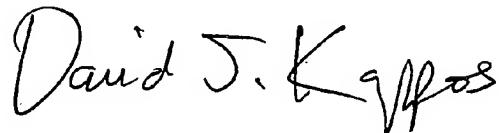
163. The process of any one of claims 1, 7, 12, 18, 19, 23, 27, 28, 32, 33, 38, 39, further including subjecting the dielectric material to a first etching of the dielectric material and a second etching of the dielectric material.

164. The device of any one of claims 83, 89, 94, 100, 101, 109, 110, 111, 114, 115, 116, 120, and 121, wherein the dielectric material is nonhomogeneous.

165. The device of any one of 83, 89, 94, 100, 101, 109, 110, 111, 114, 115, 116, 120, and 121, wherein the metal layer is comprised of a conductive coating.

Signed and Sealed this

Eleventh Day of May, 2010



David J. Kappos
Director of the United States Patent and Trademark Office